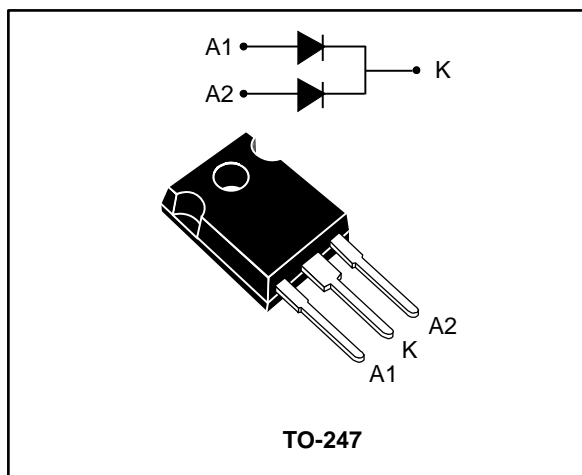


High efficiency rectifier

Datasheet - production data



Description

The STTH60W03C uses ST 300 V technology. It is especially suited to be used for DC/DC and DC/AC converters in secondary stage of MIG/MMA/TIG welding machine. Housed in ST's TO-247, this device offers high power integration for all welding machines and industrial applications.

Table 1: Device summary

Symbol	Value
$I_{F(AV)}$	2 x 30 A
V_{RRM}	300 V
T_j	175 °C
V_F (typ.)	0.94 V
t_{rr} (typ.)	25 ns

Features

- Ultrafast switching
- Low reverse current
- Low thermal resistance
- Reduced switching losses
- ECOPACK[®]2 compliant component

1 Characteristics

Table 2: Absolute ratings (limiting values, per diode, limiting values at 25°C, unless otherwise specified)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage			300	V
I _{F(RMS)}	Forward rms current			50	A
I _{F(AV)}	Average forward current $\delta = 0.5$, square wave	T _c = 110 °C	Per diode	30	A
		T _c = 95 °C	Per device	60	A
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms sinusoidal		280	A
T _{stg}	Storage temperature range			-65 to +175	°C
T _j	Maximum operating junction temperature range			+175	°C

Table 3: Thermal parameters

Symbol	Parameter		Max. value	Unit
R _{th(j-c)}	Junction to case	Per diode	1.5	°C/W
		Total	0.9	°C/W
R _{th(c)}	Coupling		0.3	°C/W

When the diodes 1 and 2 are used simultaneously:

$$\Delta T_j (\text{diode1}) = P_{(\text{diode1})} \times R_{th(j-c)} (\text{per diode}) + P_{(\text{diode2})} \times R_{th(c)}$$

Table 4: Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25 °C	V _R = V _{RRM}	-		20	μA
		T _j = 125 °C		-	20	200	
V _F ⁽²⁾	Forward voltage drop	T _j = 25 °C	I _F = 30 A	-		1.45	V
		T _j = 150 °C		-	0.94	1.15	
		T _j = 25 °C	I _F = 60 A	-		1.7	
		T _j = 150 °C		-	1.18	1.45	

Notes:

(1)Pulse test: t_p = 5 ms, $\delta < 2\%$

(2)Pulse test: t_p = 380 μs, $\delta < 2\%$

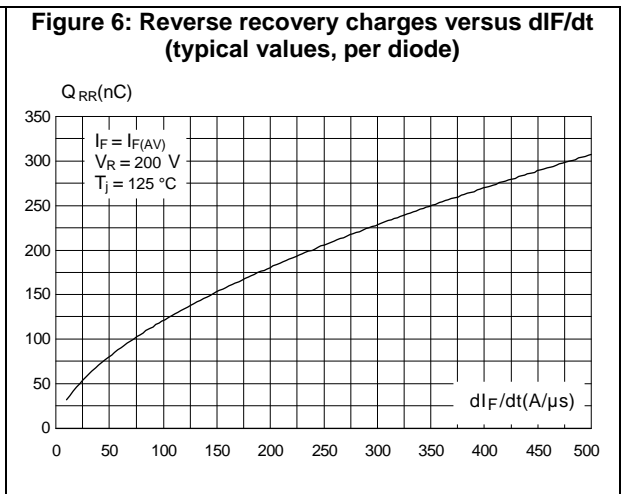
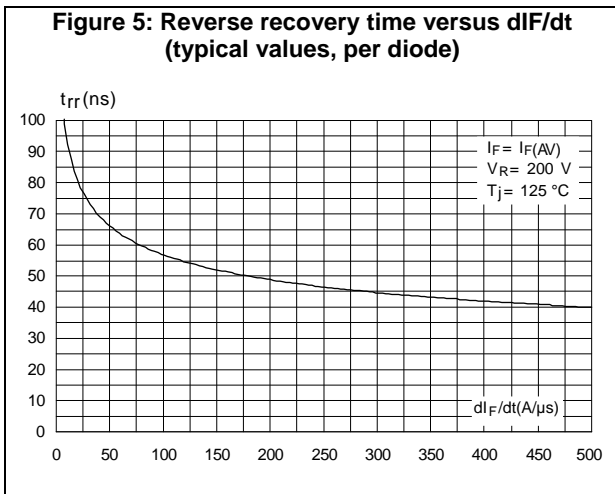
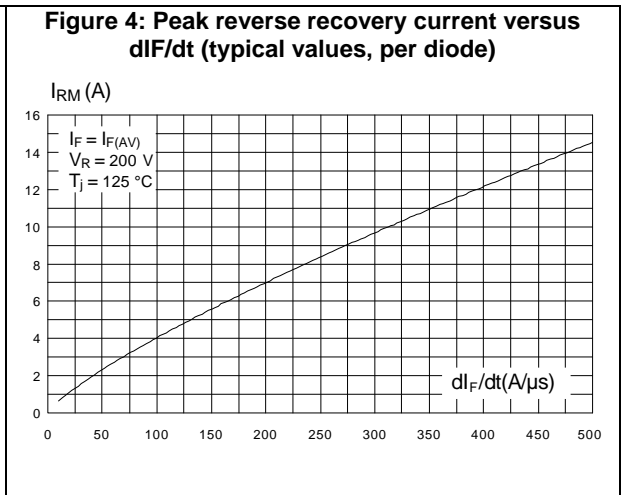
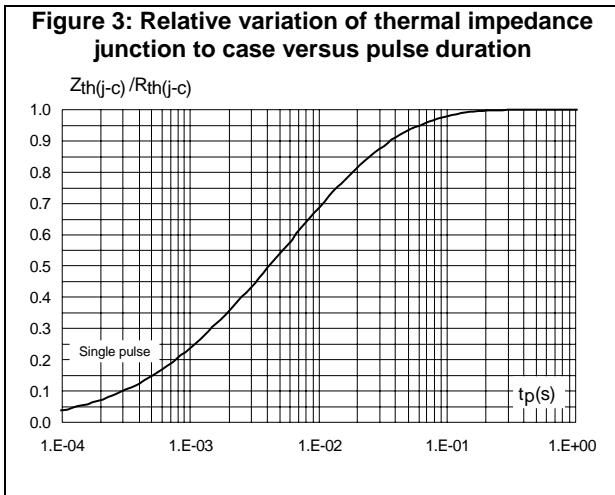
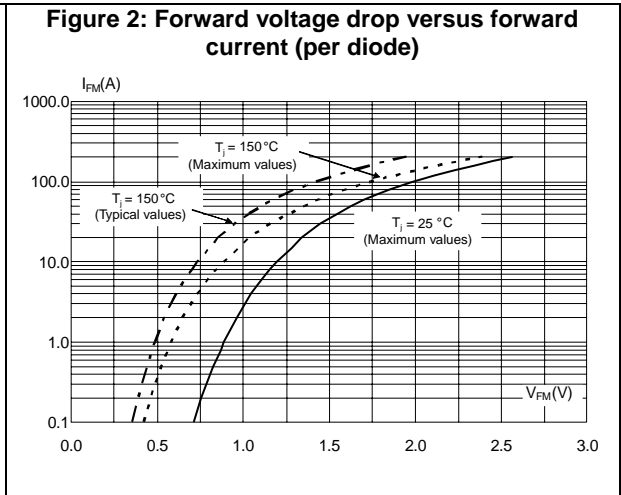
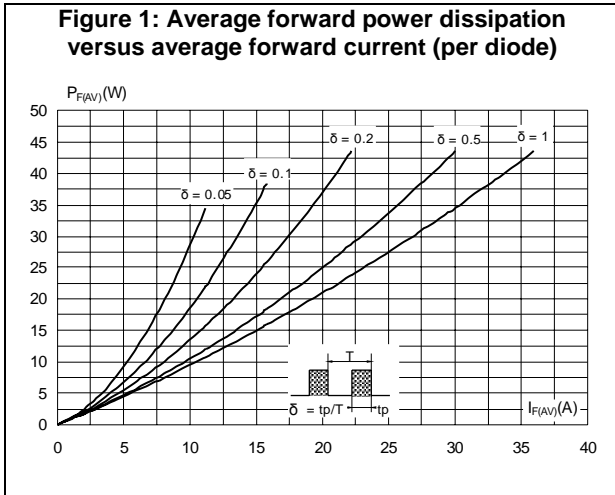
To evaluate the conduction losses, use the following equation:

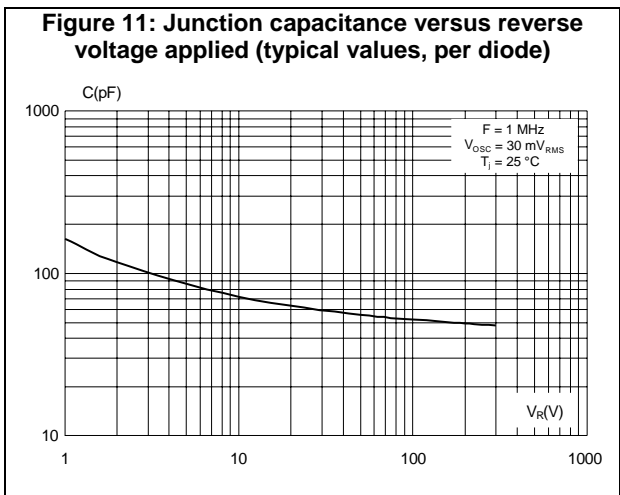
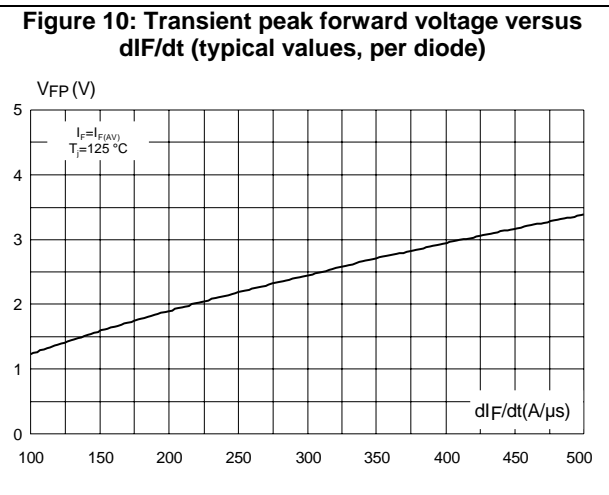
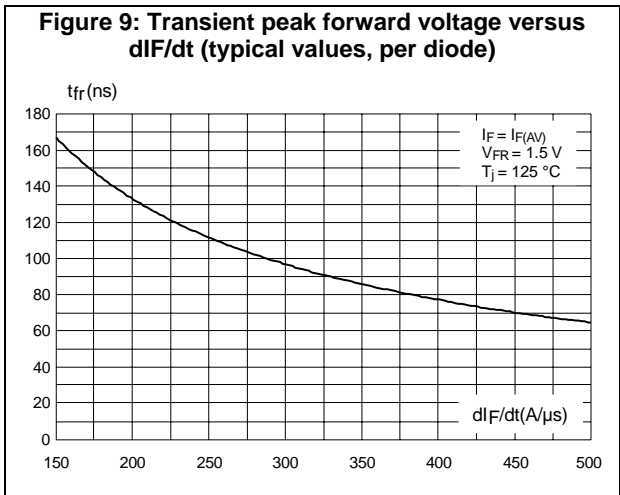
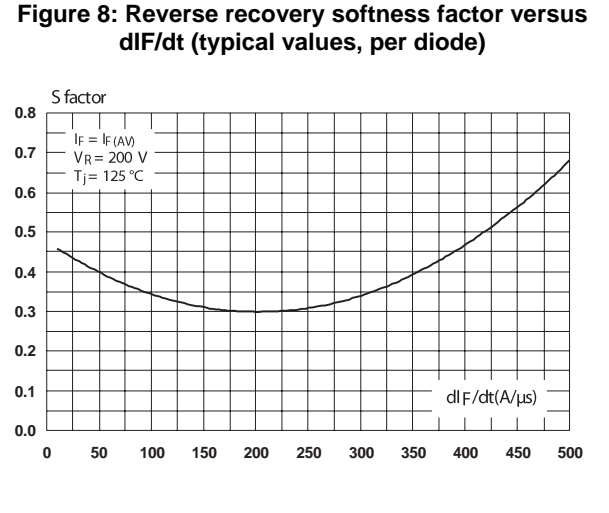
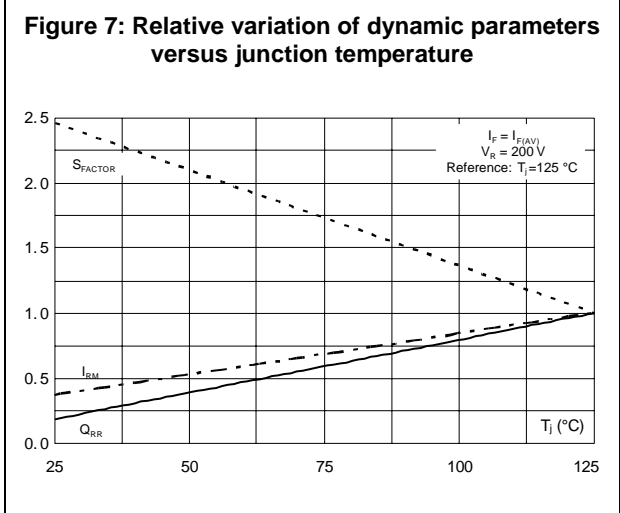
$$P = 0.85 \times I_{F(AV)} + 0.010 \times I_{F(RMS)}^2$$

Table 5: Dynamic electrical characteristics (per diode)

Symbol	Parameters	Test conditions		Min.	Typ.	Max.	Unit
I_{RM}	Reverse recovery current	$T_j = 125\text{ °C}$	$I_F = 30\text{ A}$, $V_R = 200\text{ V}$, $di_F/dt = -200\text{ A}/\mu\text{s}$	-	7	9	A
Q_{RR}	Reverse recovery charge	$T_j = 125\text{ °C}$	$I_F = 30\text{ A}$, $V_R = 200\text{ V}$, $di_F/dt = -200\text{ A}/\mu\text{s}$	-	180		nC
S_{factor}	Softness factor	$T_j = 125\text{ °C}$	$I_F = 30\text{ A}$, $V_R = 200\text{ V}$, $di_F/dt = -200\text{ A}/\mu\text{s}$	-	0.3		
t_{rr}	Reverse recovery time	$T_j = 25\text{ °C}$	$I_F = 1\text{ A}$, $di_F/dt = -100\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$	-	25	35	ns
t_{fr}	Forward recovery time	$T_j = 25\text{ °C}$	$I_F = 30\text{ A}$, $di_F/dt = 200\text{ A}/\mu\text{s}$, $V_{FR} = 1.5\text{ V}$	-		180	ns
V_{FP}	Forward recovery voltage			-	2.0	3.0	V

1.1 Characteristics (curves)





2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.8 N·m (TO-247)
- Maximum torque value: 1.0 N·m (TO-247)

2.1 TO-247 with Inches package information

Figure 12: TO-247 package outline

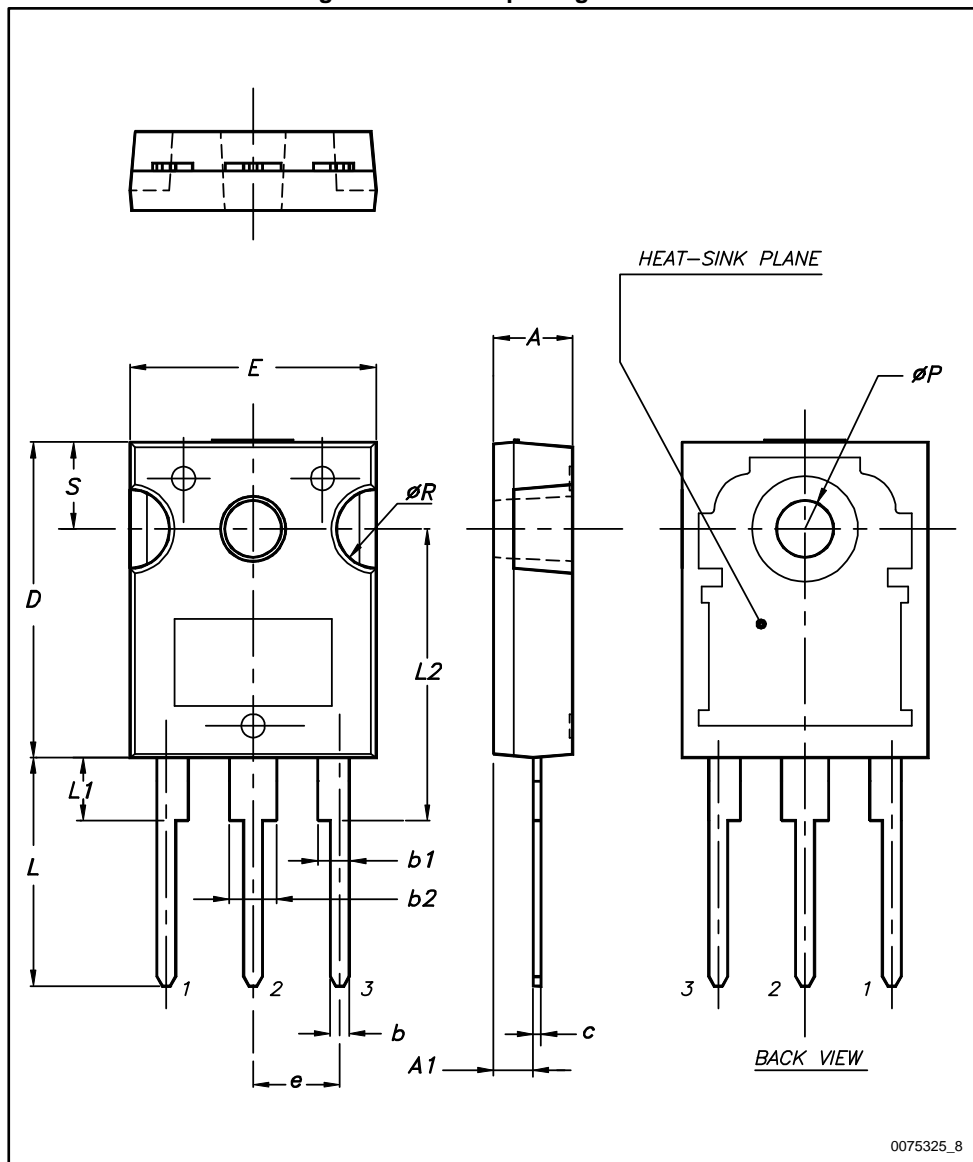


Table 6: TO-247 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.85		5.15	0.191		0.203
A1	2.20		2.60	0.086		0.102
b	1.00		1.40	0.039		0.055
b1	2.00		2.40	0.078		0.094
b2	3.00		3.40	0.118		0.133
c	0.40		0.80	0.015		0.031
D ⁽¹⁾	19.85		20.15	0.781		0.793
E	15.45		15.75	0.608		0.620
e	5.30	5.45	5.60	0.209	0.215	0.220
L	14.20		14.80	0.559		0.582
L1	3.70		4.30	0.145		0.169
L2		18.50			0.728	
ØP ⁽²⁾	3.55		3.65	0.139		0.143
ØR	4.50		5.50	0.177		0.217
S	5.30	5.50	5.70	0.209	0.216	0.224

Notes:

⁽¹⁾Dimension D plus gate protusion does not exceed 20.5 mm

⁽²⁾Resin thickness around the mounting hole is not less than 0.9 mm.

3 Ordering information

Table 7: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STTH60W03CW	STTH60W03CW	TO-247	4.43 g	50	Tube

4 Revision history

Table 8: Document revision history

Date	Revision	Changes
07-Sep-2004	1	First issue.
08-Feb-2018	2	Updated Description and package information.

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